Remarks

Claims 1-20 stand finally rejected under 35 U.S.C. 102(e) as allegedly anticipated by U.S. Patent Application Publication 2002/0191349 to Hsu et al. (Hsu).

Anticipation requires the presence in a single prior art reference disclosure of each and every element of the claimed invention, arranged as in the claim. <u>Lindemann</u>

<u>Maschinenfabrik GmbH v. American Hoist & Derrick Co.</u>, 221 USPQ 481, 485 (Fed. Cir. 1984).

Applicants have carefully reviewed Hsu, the Office Action and the claims at issue, and respectfully assert that none of the claims are anticipated by Hsu.

A. Claims 1-7

Claim 1 includes the limitations of:

"forming an inorganic nonferromagnetic apex region having a first side that is substantially parallel to said surface and a second side that is not parallel to said surface and not perpendicular to said surface;" and

"forming a second soft magnetic pole layer over said inorganic nonferromagnetic apex region, such that said second pole layer has an interface that is substantially equidistant from said second side."

Hsu does not teach or suggest "forming a second soft magnetic pole layer over said inorganic nonferromagnetic apex region, such said second pole layer has an interface that is substantially equidistant from said second side." Instead, Hsu states in paragraph [0068]: "An important aspect of the invention, however, is that the profile of the first write coil layer 206 is not replicated into the second write coil layer 230 because of the thick alumina layer 226 therebetween." See also the "SUMMARY OF THE INVENTION," paragraph [0013], which teaches: "A thick insulation layer, which is preferably alumina, is provided between the bottom and top write coils so as to provide an effective heat sink for the top coil. The thick insulation layer is planarized so as to eliminate any profile of the bottom coil being replicated into the top coil."

For at least this reason, claim 1 and all of the claims that depend from claim 1 are not anticipated by Hsu.

Claim 2 includes the limitation that "forming said inorganic nonferromagnetic apex includes etching said hardbaked photoresist mask and said inorganic nonferromagnetic layer to create said inorganic nonferromagnetic apex region."

Hsu, in contrast, states in paragraphs 58 and 65 that "alumina layer 210" is "planarized," and does not teach etching the "alumina layer 210."

Claim 3 includes the limitation of "forming a photoresist mask over said inorganic nonferromagnetic layer, said mask terminating adjacent to a desired location of said second side."

Hsu, in contrast, shows in FIG. 10A that "alumina layer 210" is formed on "hardbaked photoresist 208."

Claim 4 includes the limitation of "chemically etching said inorganic nonferromagnetic layer."

Hsu, in contrast, states in paragraphs 58 and 65 that "alumina layer 210" is "planarized," and does not teach etching the "alumina layer 210."

B. Claims 8-14

Claim 8 includes the limitation of "etching said hardbaked photoresist mask and said inorganic nonferromagnetic layer." Applicants respectfully disagree with the Office Action assertion that Hsu teaches this limitation. Paragraph [0071] and FIG. 10A of Hsu do not teach this limitation. Instead, Hsu states in paragraphs 58 and 65 that "alumina layer 210" is "planarized," and does not teach etching the "alumina layer 210."

Claim 8 also includes the limitation of "including removing said hardbaked photoresist mask." Applicants respectfully disagree with the Office Action assertion that Hsu teaches this limitation.

Claims 9-14 are not anticipated by Hsu for at least the reasons mentioned above regarding claim 8.

In addition, claim 10 includes the limitation of "wherein forming said region of inorganic nonferromagnetic material includes etching said inorganic nonferromagnetic layer into a shape that substantially duplicates a shape of said mask." An example of such a method is shown in FIG. 5 and FIG. 6 of the present application. This limitation is not taught or suggested in Hsu.

Further, claim 14 includes the limitations of "forming an inorganic dielectric layer that partly covers said first soft magnetic layer, prior to forming said inorganic nonferromagnetic layer;" and "positioning said mask such that said region of inorganic nonferromagnetic material is disposed partly on said first soft magnetic layer and partly on said inorganic dielectric layer." Neither of these limitations are taught or suggested in Hsu.

C. Claims 15-20

Claim 15 includes the limitation of "a step for forming a second soft magnetic pole layer over said inorganic nonferromagnetic apex region, such that said second pole layer has a region that is substantially parallel to said sloping surface and disposed within one micron of said sloping surface."

Applicants respectfully assert that Hsu does not teach this limitation. Instead, Hsu states in paragraph [0068]: "An important aspect of the invention, however, is that the profile of the first write coil layer 206 is not replicated into the second write coil layer 230 because of the thick alumina layer 226 therebetween." See also the "SUMMARY OF THE INVENTION," paragraph [0013], which teaches: "A thick insulation layer, which is preferably alumina, is provided between the bottom and top write coils so as to provide an effective heat sink for the top coil. The thick insulation layer is planarized so as to eliminate any profile of the bottom coil being replicated into the top coil."

Claim 16 includes the limitation of "etching said hardbaked photoresist mask and said inorganic nonferromagnetic layer to create said inorganic nonferromagnetic apex region." Applicants respectfully disagree with the Office Action assertion that Hsu teaches "chemically etching the hardbaked photoresist mask and the inorganic nonferromagnetic apex region."

Claim 18 includes the limitation of "chemically etching said inorganic nonferromagnetic layer." Applicants respectfully disagree with the Office Action assertion that paragraph [0071] and FIG. 10A of Hsu teaches "chemically etching the hardbaked photoresist mask and the inorganic nonferromagnetic apex region."

Conclusion:

Applicants respectfully assert that he Office Action does not present a prima facie case of anticipation. As such, applicants believe that the claims are in condition for allowance, and a Notice of Allowance is solicited.

Respectfully submitted,

CERTIFICATE OF MAILING

I hereby certify that this correspondence is being deposited with the United States Postal Service as first class mail in an envelope addressed to: MS AF, P.O. Box 1450, Commissioner for Patents, Alexandria, VA 22313-1450, on September 30, 2003.

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